

PMBT3906

PNP switching transistor Rev. 06 — 2 March 2010

Product data sheet

Product profile

1.1 General description

PNP switching transistor in a SOT23 (TO-236AB) small Surface-Mounted Device (SMD) plastic package.

NPN complement: PMBT3904.

1.2 Features and benefits

- Collector-emitter voltage V_{CEO} = -40 V
- Collector current capability I_C = -200 mA

1.3 Applications

General amplification and switching

1.4 Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------|---------------------------|------------|-----|-----|------|------|
| V_{CEO} | collector-emitter voltage | open base | - | - | -40 | V |
| I _C | collector current | | - | - | -200 | mA |

Pinning information 2.

Table 2. **Pinning**

| Pin | Description | Simplified outline | Graphic symbol |
|-----|-------------|--------------------|----------------|
| 1 | base | | |
| 2 | emitter | 3 | 3 |
| 3 | collector | 12 | 1— |
| | | | 006aab259 |



3. Ordering information

Table 3. Ordering information

| Type number | Package | | |
|-------------|---------|--|---------|
| | Name | Description | Version |
| PMBT3906 | - | plastic surface-mounted package; 3 leads | SOT23 |

4. Marking

Table 4. Marking codes

| Type number | Marking code ^[1] |
|-------------|-----------------------------|
| PMBT3906 | *2A |

[1] * = -: made in Hong Kong

* = p: made in Hong Kong

* = t: made in Malaysia

* = W: made in China

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| V _{CBO} collector-base voltage open emitter - -40 V _{CEO} collector-emitter voltage open base - -40 | V V |
|---|--------|
| <u> </u> | V |
| V spritter been valtered and collector | |
| V _{EBO} emitter-base voltage open collector6 | V |
| I _C collector current200 | mA |
| I _{CM} peak collector current200 | mA |
| I _{BM} peak base current100 | mA |
| P_{tot} total power dissipation $T_{amb} \le 25 ^{\circ}\text{C}$ [1] - 250 | mW |
| T _j junction temperature - 150 | °C |
| T _{amb} ambient temperature -65 +150 | °C |
| T _{stg} storage temperature –65 +150 | °C |

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB).

6. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------------|---|-------------|--------------|-----|-----|------|
| $R_{th(j-a)}$ | thermal resistance from junction to ambient | in free air | <u>[1]</u> _ | - | 500 | K/W |

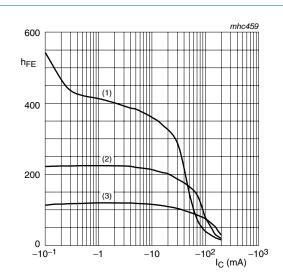
^[1] Device mounted on an FR4 PCB.

7. Characteristics

Table 7. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

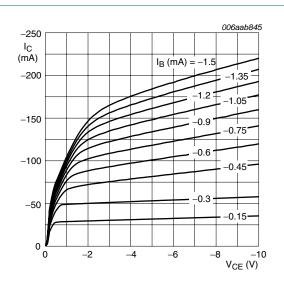
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|--------------------|---|--|-----|------|------|------|
| I _{CBO} | collector-base cut-off current | $V_{CB} = -30 \text{ V}; I_E = 0 \text{ A}$ | - | - | -50 | nA |
| I _{EBO} | emitter-base cut-off current | $V_{EB} = -6 \text{ V}; I_C = 0 \text{ A}$ | - | - | -50 | nA |
| h _{FE} | DC current gain | $V_{CE} = -1 V$ | | | | |
| | | $I_C = -0.1 \text{ mA}$ | 60 | - | - | |
| | | $I_C = -1 \text{ mA}$ | 80 | - | - | |
| | | $I_C = -10 \text{ mA}$ | 100 | - | 300 | |
| | | $I_C = -50 \text{ mA}$ | 60 | - | - | |
| | | $I_C = -100 \text{ mA}$ | 30 | - | - | |
| V_{CEsat} | collector-emitter | $I_C = -10 \text{ mA}; I_B = -1 \text{ mA}$ | - | - | -250 | mV |
| saturation voltage | $I_C = -50 \text{ mA}; I_B = -5 \text{ mA}$ | - | - | -400 | mV | |
| V _{BEsat} | base-emitter saturation voltage | $I_C = -10 \text{ mA}; I_B = -1 \text{ mA}$ | - | - | -850 | mV |
| | | $I_C = -50 \text{ mA}; I_B = -5 \text{ mA}$ | - | - | -950 | mV |
| t _d | delay time | $I_{Con} = -10 \text{ mA};$ | - | - | 35 | ns |
| t _r | rise time | $I_{Bon} = -1 \text{ mA};$ | - | - | 35 | ns |
| t _{on} | turn-on time | I _{Boff} = 1 mA | - | - | 70 | ns |
| t _s | storage time | | - | - | 225 | ns |
| t _f | fall time | | - | - | 75 | ns |
| t _{off} | turn-off time | | - | - | 300 | ns |
| f _T | transition frequency | $V_{CE} = -20 \text{ V};$ $I_{C} = -10 \text{ mA};$ $f = 100 \text{ MHz}$ | 250 | - | - | MHz |
| C _c | collector capacitance | $V_{CB} = -5 \text{ V; } I_E = i_e = 0 \text{ A;}$ f = 1 MHz | - | - | 4.5 | pF |
| C _e | emitter capacitance | $V_{EB} = -500 \text{ mV};$ $I_C = i_c = 0 \text{ A}; f = 1 \text{ MHz}$ | - | - | 10 | pF |
| NF | noise figure | $I_C = -100 \mu A;$ $V_{CE} = -5 V; R_S = 1 kΩ;$ f = 10 Hz to 15.7 kHz | - | - | 4 | dB |



$$V_{CE} = -1 V$$

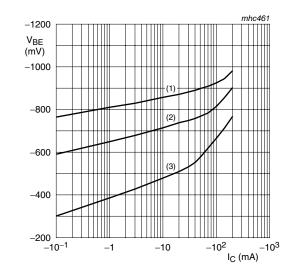
- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -55 \, ^{\circ}C$

Fig 1. DC current gain as a function of collector current; typical values



 $T_{amb} = 25 \, ^{\circ}C$

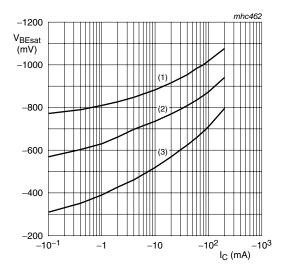
Fig 2. Collector current as a function of collector-emitter voltage; typical values





- (1) $T_{amb} = -55 \,^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = 150 \, ^{\circ}C$

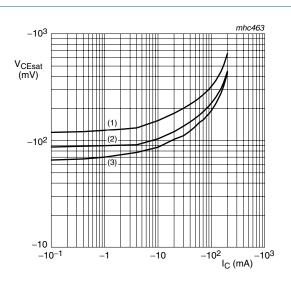
Fig 3. Base-emitter voltage as a function of collector current; typical values



 $I_{\rm C}/I_{\rm B} = 10$

- (1) $T_{amb} = -55 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = 150 \, ^{\circ}C$

Fig 4. Base-emitter saturation voltage as a function of collector current; typical values



 $I_{\rm C}/I_{\rm B}=10$

- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -55 \, ^{\circ}C$

Fig 5. Collector-emitter saturation voltage as a function of collector current; typical values

8. Test information

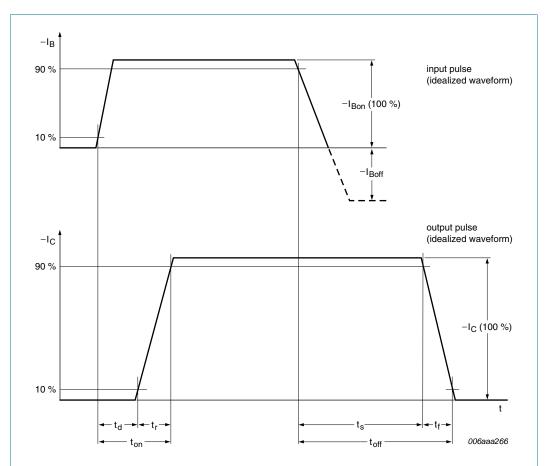
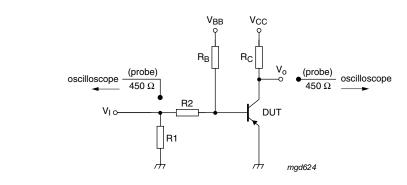


Fig 6. BISS transistor switching time definition



 $V_I = 5~V;~T = 500~\mu s;~t_p = 10~\mu s;~t_r = t_f \leq 3~ns$

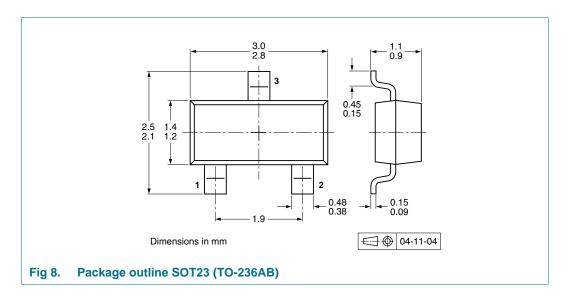
R1 = 56 Ω ; R2 = 2.5 k Ω ; R_B = 3.9 k Ω ; R_C = 270 Ω

 V_{BB} = 1.9 V; V_{CC} = -3 V

Oscilloscope: input impedance $Z_i = 50 \Omega$

Fig 7. Test circuit for switching times

9. Package outline



10. Packing information

Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

| Type number | Package | Description | Packing quantity | |
|-------------|---------|--------------------------------|------------------|-------|
| | | | 3000 | 10000 |
| PMBT3906 | SOT23 | 4 mm pitch, 8 mm tape and reel | -215 | -235 |

^[1] For further information and the availability of packing methods, see Section 13.

11. Revision history

Table 9. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes | | |
|----------------|---|------------------------------|---------------|----------------|--|--|
| PMBT3906_6 | 20100302 | Product data sheet | - | PMBT3906_N_5 | | |
| Modifications: | The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. | | | | | |
| | Legal texts have been adapted to the new company name where appropriate. | | | | | |
| | Section 4 "Marking": amended | | | | | |
| | <u>Table 7 "Characteristics"</u> : F redefined to NF noise figure | | | | | |
| | Section 8 "Test information": added | | | | | |
| | • Figure 6: added | | | | | |
| | Figure 8: superseded by minimized package outline drawing | | | | | |
| | Section 10 "Packing information": added | | | | | |
| | Section 12 | "Legal information": updated | b | | | |
| PMBT3906_N_5 | 20071004 | Product data sheet | - | PMBT3906_4 | | |
| PMBT3906_4 | 20040121 | Product specification | - | PMBT3906_3 | | |
| PMBT3906_3 | 19990427 | Product specification | - | PMBT3906_CNV_2 | | |
| PMBT3906_CNV_2 | 19970505 | Product specification | - | - | | |
| | | | | | | |

12. Legal information

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| Document status[1][2] | Product status[3] | Definition |
|--------------------------------|-------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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PMBT3906 NXP Semiconductors

PNP switching transistor

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